

MA150, MA161, MA162, MA162A

Silicon epitaxial planer type

For switching circuits

■ Features

- Short reverse recovery period t_{rr}
- Small capacity between pins, C_t

■ Absolute Maximum Ratings (Ta= 25°C)

Parameter	Symbol	Rating	Unit
Reverse voltage (DC)	V_R	MA150 35	V
		MA161 50	
		MA162 75	
		MA162A 120	
Repetitive peak reverse voltage	V_{RRM}	MA150 35	V
		MA161 50	
		MA162 75	
		MA162A 120	
Average forward current	$I_{F(AV)}$	100	mA
Repetitive peak forward current	I_{FRM}	225	mA
Non-repetitive peak forward surge current	I_{FSM}^*	500	mA
Junction temperature	T_j	200	°C
Storage temperature	T_{stg}	- 55 to + 200	°C

* $t=1s$

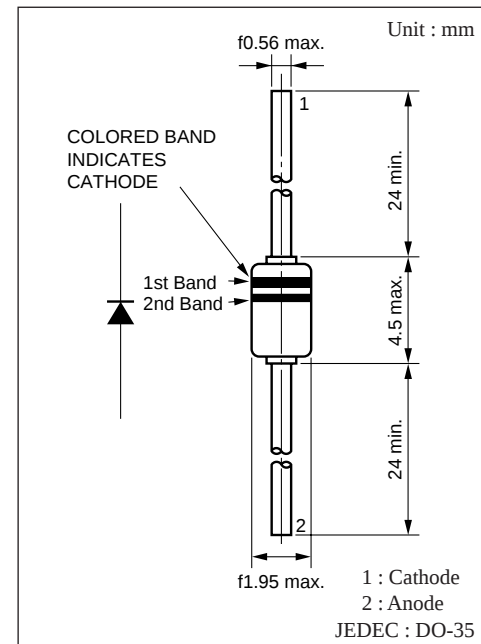
■ Electrical Characteristics (Ta= 25°C)

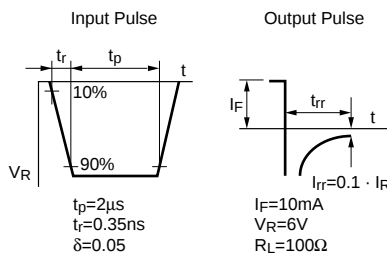
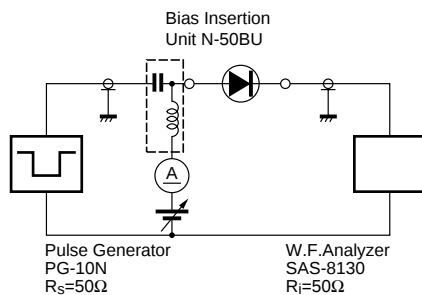
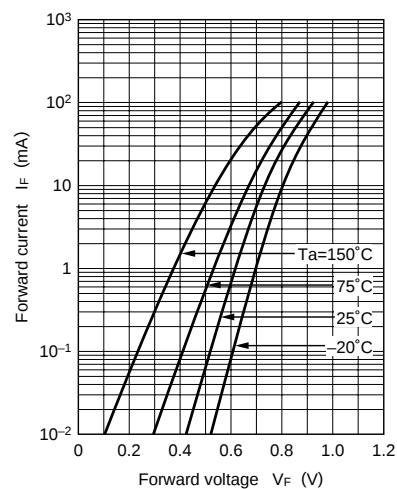
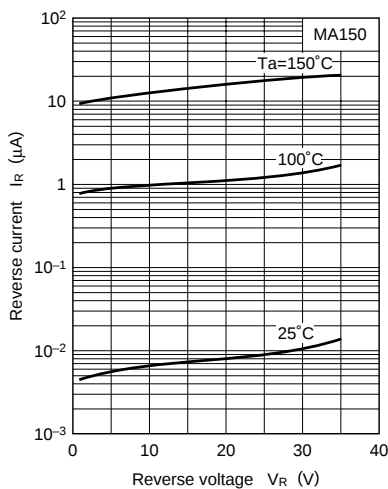
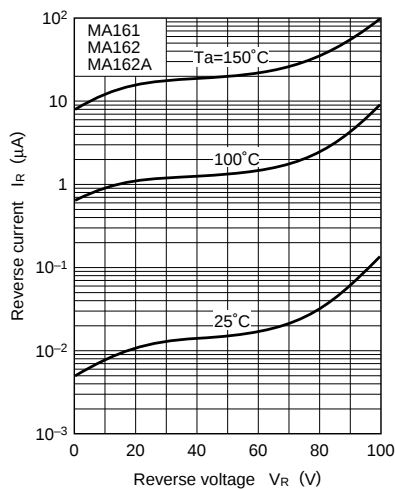
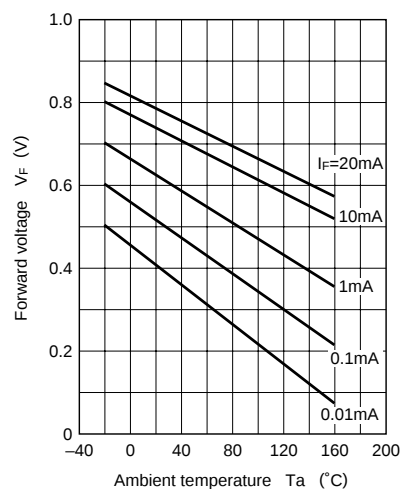
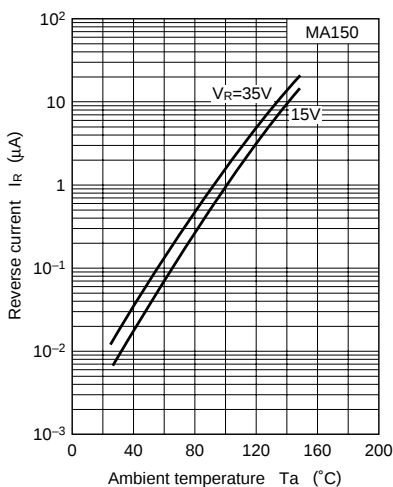
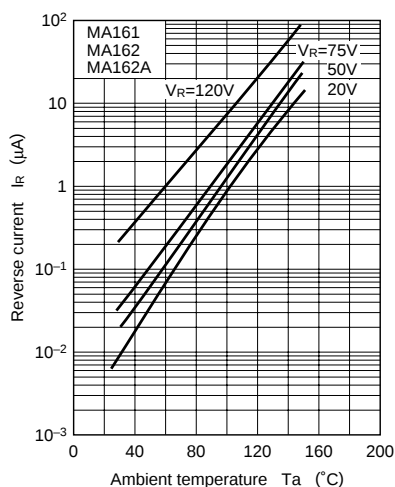
Parameter	Symbol	Condition	min	typ	max	Unit
Reverse current (DC)	MA150	$V_R=15V$			0.025	μA
		$V_R= 30V$			0.1	
	MA161	$V_R=15V$			0.025	
		$V_R= 50V$			5	
	MA162	$V_R= 20V$		0.012	0.025	
		$V_R= 75V$		0.1	5	
	MA162A	$V_R= 20V$		0.012	0.025	
		$V_R=120V$			5	
	MA150	$V_R= 35V, T_a= 150^\circ C$			100	
	MA161	$V_R= 50V, T_a=150^\circ C$			100	
		I_R				
Forward voltage (DC)	V_F	$I_F=100mA$		0.95	1.2	V
Reverse voltage (DC)	MA150	V_R	$I_R= 5\mu A$	35		V
Terminal capacitance	C_t	$V_R= 0V, f=1MHz$		0.9	2	pF
Reverse recovery time	MA150	t_{rr}^*	$I_F=10mA, V_R=1V, R_L=100\Omega,$ Measure when $I_R= 0.1 \cdot I_R$		10	ns
	MA161/162/162A			2.2	4	

❖ Rated input/output frequency : 100MHz

■ Cathode Indication

Type No.		MA150	MA161	MA162	MA162A
Color	1st Band	White	Green	Violet	Black
	2nd Band	—	—	—	Black



* t_{rr} measuring circuit $I_F - V_F$  $I_F - V_F$  $I_R - V_R$  $V_F - T_a$  $I_R - T_a$  $I_R - T_a$  $C_t - V_R$ 